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Silicon N-Channel Power F-MOS FET

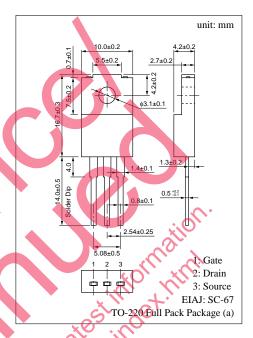
■ Features

- High avalanche energy capacity
- V_{GSS}: 30V guaranteed
- Low R_{DS(on)}, high-speed switching characteristic

■ Applications

- High-speed switching (switching power supply, AC adaptor)
- For high-frequency power amplification
- Absolute Maximum Ratings $(T_C = 25^{\circ}C)$

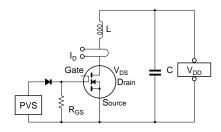
Parameter		Symbol	Ratings	Unit	
Drain to Source breakdown voltage		V _{DSS}	800	V	
Gate to Source voltage		V _{GSS}	±30	V	
Drain current	DC	I _D ±3		A	
	Pulse	I_{DP}	±6	A	
Avalanche energy capacity		EAS*	20	mJ	
Allowable power	$T_C = 25^{\circ}C$	D	50	W	
dissipation	$Ta = 25^{\circ}C$	P _D	2		
Channel temperature		T_{ch}	150	°C	
Storage temperature		T _{stg}	-55 to +150	°C	



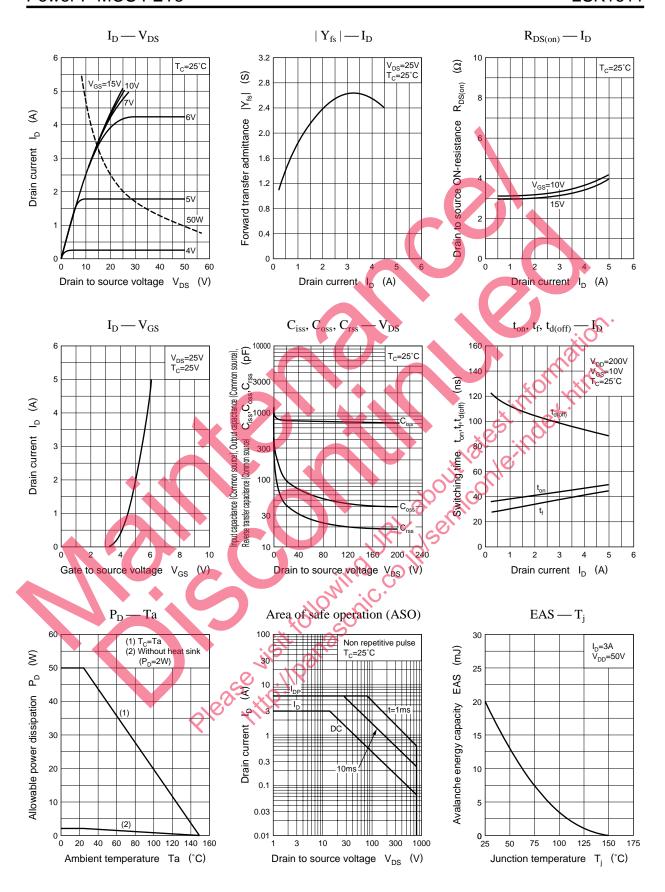
■ Electrical Characteristics (T_C = 25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	$I_{ m DSS}$	$V_{DS} = 640V, V_{GS} = 0$.ell		0.1	mA
Gate to Source leakage current	I_{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0$	0		±1	μΑ
Drain to Source breakdown voltage	V _{DSS}	$I_D = 1 \text{mA}, V_{GS} = 0$	800			V
Avalanche energy capacity	EAS*	$L = 4.5 \text{mH}, I_D = 3A, V_{DD} = 50 \text{V}$	20			mJ
Gate threshold voltage	V _{th}	$V_{DS} = 25V$, $I_D = 1mA$	1		5	V
Drain to Source ON-resistance	R _{DS(on)}	$V_{GS} = 10V, I_D = 2A$		3.2	4	Ω
Forward transfer admittance	Y _{fs}	$V_{DS} = 25V, I_{D} = 2A$	1.5	2.4		S
Input capacitance (Common Source)	C _{iss}	11.100		730		pF
Output capacitance (Common Source)	Coss	$V_{DS} = 20V, V_{GS} = 0, f = 1MHz$		90		pF
Reverse transfer capacitance (Common Source)	Crs	Hill		40		pF
Turn-on time	t _{on}	V 10V I 24		40		ns
Fall time	t_{f}	$V_{GS} = 10V, I_D = 2A$		35		ns
Turn-off time (delay time)	t _{d(off)}	$V_{DD} = 200V, R_L = 100\Omega$		105		ns

^{*} Avalanche energy capacity test circuit



^{*} Single pulse



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